Diode Semiconductor Device - Page 1 of 1



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Inclosure Materi	ai.
Glass	
Overall Length:	
	ches and 0.560 inches
Terminal Length	
1.000 inches	
Overall Diameter	
	ches and 0.265 inches
	ally-electrically Connected To Case:
Cathode	
Mounting Metho	d:
Terminal	
Features Provide	ed:
Hermetically seal	ed case
Semiconductor	Material:
Silicon	
Voltage Rating I	n Volts Per Characteristic:
68.0 regulator vo	bltage
Current Rating F	Per Characteristic:
14.00 milliampere	es source cutoff current horsepower metric
Power Rating Pe	er Characteristic:
1.0 watts small-si	gnal input power, common-collector preset
Maximum Opera	ting Tempurature Per Measurement Point:
175.0 degrees ce	Isius ambient air
Test Data Docun	nent:
81349-mil-s-1950	0 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental an	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	nd Quantity:
2 uninsulated wire	e lead
Specification Da	ta:
81349-mil-s-1950	0/115 government specification
Shelf Life:	
N/a	
Unit Of Measure	:
Demilitarization:	
No	
Fiig:	
A110a0	